

Continental Device India Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

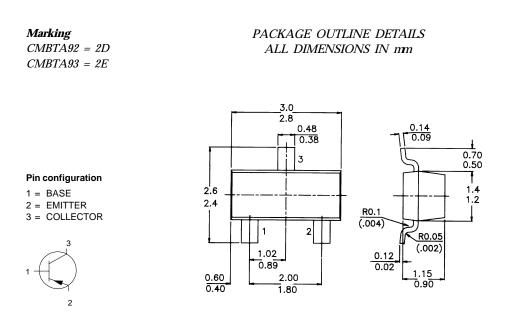


SOT-23 Formed SMD Package

CMBTA92 **CMBTA93**

SILICON EPITAXIAL TRANSISTORS

P-N-P transistor



ABSOLUTE MAXIMUM RATINGS

		CNIBI A	
Collector-base voltage (open emitter)	$-V_{CBO}$	max.	3
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	3
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	
Collector current (d.c.)	$-I_C$	max.	
Total power dissipation up to $T_{amb} = 25 \ ^{\circ}C$	P _{tot}		
D.C. current gain			
$-I_C = 10 \text{ mA}; -V_{CE} = 10 \text{ V}$	h _{FE}	min.	
Transition frequency at f = 100 MHz			
$-I_C = 10 \text{ mA}; -V_{CE} = 20 \text{ V}$	f_T	min.	
Collector-base capacitance at f = 1 MHz			
$I_E = 0; -V_{CB} = 20 V$	C _{cb}	max.	

	CMB	ГА92	A93			
$-V_{CBC}$) max.	300		200 V		
$-V_{CEC}$) max.	300		200 V		
$-V_{EBC}$) max.		5	V		
$-I_C$	max.		500	mA		
P _{tot}			250	mW		
h _{FE}	min.		40			
f_T	min.		50	MHz		
C _{cb}	max.	6		<u>8</u> pF		

CMBTA92 CMBTA93

RATINGS (at $T_A = 25^{\circ}C$ unless otherwise specified) Limiting values

Linning vindes				
		CMBTA92	A9.	3
Collector-base voltage (open emitter)	$-V_{CBO}$	max. 300	200	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max. 300	200	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_C$	max.	500	mА
Total power dissipation up to $T_{amb} = 25 \ ^{\circ}C$	P _{tot}	max	250	mW
Storage temperature	Tstg	-2	55 to +150	° C
Junction temperature	Τj	max.	150	° C

THERMAL CHARACTERISTICS

$T_j = P (R_{th j-t} + R_{th t-s} + R_{th s-a}) + T_{at}$	mb		
Thermal resistance			
from junction to ambient	R _{th j-a}	500	K/W

CHARACTERISTICS (at $T_A = 25^{\circ}C$ unless otherwise specified)

Collector-emitter breakdown voltage						
$-I_C = 1 mA; I_B = 0$	$-V_{(BR)CEC}$) min.	300		200	V
Collector-base breakdown voltage	. ,					
$-I_C = 100 \ \mu A; \ I_E = 0$	-V(BR)CBC) <i>min.</i>	300		200	V
Collector cut-off current						
$-V_{CB} = 200 \ V; \ I_E = 0$	-I _{CBO}	max.	0.25		-	μA
$-V_{CB} = 160 V; I_E = 0$	-ICBO	max.	-		0.25	μA
Emitter-base breakdown voltage						
$-I_E = 100 \ \mu A; \ I_C = 0$	-V _{(BR)EBO}	min.		5		V
Emitter cut-off current						
$I_C = 0; -V_{BE} = 3 V;$	$-I_{EBO}$	max.	0.1		0.1	$\mathfrak{m}A$
Collector-base capacitance at f= 1 MHz						
$I_E = 0; -V_{CB} = 20 V$	C _{cb}	max.	6		8	рF
Saturation voltages						
$-I_C = 20 mA; -I_B = 2 mA$	-V _{CEsat}	max.	0.5		0.5	V
$-I_C = 20 mA; -I_B = 2 mA$	-VBEsat	max.	0.9		0.9	V
D.C. current gain						
$-I_C = 1 mA; -V_{CE} = 10 V$	h _{FE}	min.		25		
$-I_C = 10 mA; -V_{CE} = 10 V$	h _{FE}	min.		40		
$-I_C = 30 \text{ mA}; -V_{CE} = 10 \text{ V}$	h _{FE}	min.		25		

Customer Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-2579 6150, 5141 1112 Fax +q 91-11-2579 5290, 5141 1119 email@cdil.com www.cdilsemi.com

Continental Device India Limited

Data Sheet

Page 3 of 3